



# HIGH EFFICIENCY MONOLITHIC SYNCHRONOUS STEP DOWN REGULATOR

- 2.7V TO 5.5V BATTERY INPUT RANGE
- HIGH EFFICIENCY: UP TO 95%
- INTERNAL SYNCHRONOUS SWITCH
- NO EXTERNAL SCHOTTKY REQUIRED
- EXTREMELY LOW QUIESCENT CURRENT
- 800mA MAX OUTPUT CURRENT
- ADJUSTABLE OUTPUT VOLTAGE FROM 0.6V
- LOW DROP-OUT OPERATION: UP TO100% DUTY CYCLE
- SELECTABLE LOW NOISE/LOW CONSUMPTION MODE AT LIGHT LOAD
- **LOW BATTERY INPUT**
- **LOW BATTERY OUTPUT**
- ±1% OUTPUT VOLTAGE ACCURACY
- CURRENT-MODE CONTROL
- 600kHz SWITCHING FREQUENCY
- EXTERNALLY SYNCHRONIZABLE FROM 500kHz TO 1.4MHz
- OVP
- SHORT CIRCUIT PROTECTION

#### **APPLICATIONS**

- BATTERY-POWERED EQUIPMENTS
- **PORTABLE INSTRUMENTS**
- CELLULAR PHONES
- PDAs AND HAND HELD TERMINALS
- DSC
- GPS

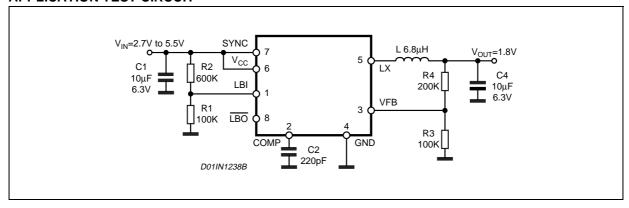


#### **DESCRIPTION**

The device is dc-dc monolithic regulator specifically designed to provide extremely high efficiency.

The device has on UVLO set at 2.7V cause it is particurarly thought for single Li-ion cell applications. Output voltage can be selected by an external divider down to 0.6V. Duty Cycle can saturate to 100% allowing low drop-out operation. The device is based on a 600kHz fixed-frequency, current mode-architecture. Low Consumption Mode operation can be selected at light load conditions, allowing switching losses to be reduced. L6925D is externally synchronizable with a clock which makes it useful in noisesensitive applications. LBI pin can be used to have a LBO signal when the Battery voltage is lower than a preset value. Other features like, Overvoltage protection, Shortcircuit protection and Thermal Shutdown (150°C) are also present.

#### **APPLICATION TEST CIRCUIT**

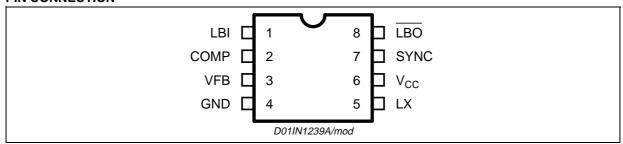


September 2003 1/5

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>6</sub>	Input voltage	-0.3 to 6	V
V <sub>5</sub>	Output switching voltage	-1 to V <sub>CC</sub>	V
V <sub>1</sub>	Shutdown	-0.3 to V <sub>CC</sub>	V
V <sub>3</sub>	Feedback voltage	-0.3 to V <sub>CC</sub>	V
V <sub>2</sub>	Analog input voltage	-0.3 to V <sub>CC</sub>	V
P <sub>tot</sub>	Power dissipation at Tamb=70°C	0.45	W
Tj	Junction operating temperature range	-40 to 150	°C
T <sub>stg</sub>	Storage temperature range	-65 to 150	°C
LX Pin	Maximum Withstanding Voltage Range Test Condition: CDF-	±1000	V
Other pins	AEC-Q100-002- "Human Body Model" Acceptance Criteria: "Normal Performance"	±2000	V

### **PIN CONNECTION**



#### THERMAL DATA

Symbo	Parameter	Value	Unit
R <sub>th j-am</sub>	Thermal Resistance Junction to Ambient	180	°C/W

#### **PIN FUNCTIONS**

N	Name	Description					
1	LBI	Battery low voltage detector input. The internal threshold is set to 0.6V. The external threshold can be adjusted by using an external resistor divider.					
2	COMP	Error amplifier output. Compensate it with a 220pF capacitor					
3	VFB	Error amplifier input. The output voltage can be adjusted by using an external resistor divider connected to this pin ( $V_{FB} = 0.6V$ ).					
4	GND	Ground.					
5	LX	Switch node connection to the inductor.					
6	VCC	Input voltage.					
7	SYNC	This pin allows to select Low Noise/ Low Consumption Mode or to sychronize the device.					
8	LBO	Battery low voltage detector output. If the voltage at the LBI pin drops below the internal thrshold, LBO goes low. The LBO is an open drain output. A pull_up resistor should be connected between the pin and the output voltage					

2/5

## **ELECTRICAL CHARACTERISTICS** ( $T_J = 25^{\circ}C$ , $V_{CC} = 3.6V$ unless otherwise specified)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V <sub>cc</sub>	Operating input voltage	After Turn On	2.7		5.5	V
V <sub>cc ON</sub>	Turn On threshold			2.8		V
V <sub>cc OFF</sub>	Turn Off threshold			2.65		V
V <sub>cc hys</sub>	Hysteresis			150		mV
Rp	High side Ron	$V_{cc} = 3.6V, I_{IX} = 100mA$		240		mΩ
R <sub>n</sub>	Low side Ron	$V_{cc} = 3.6V$ , $I_{lx} = 100$ mA		215		mΩ
I <sub>lim</sub>	Peak current limit	V <sub>cc</sub> = 3.6V		1.2		Α
	Valley current limit	V <sub>cc</sub> = 3.6V		1.4		А
V <sub>out</sub>	Output voltage range		0.6		Vcc	V
f <sub>osc</sub>	Oscillator frequency			600		KHz
f <sub>sync</sub>	Sync mode clock (*)		500		1400	KHz
DC CHARA	CTERISTICS			I	·L	L
Iq	Quiescent current (low noise mode)	V <sub>sync</sub> = 0V, no load, V <sub>FB</sub> > 0.6V		230		μΑ
	Quiescent current (low cunsumption mode)	$V_{\text{sync}} = V_{\text{cc}}$ , no load, $V_{\text{FB}} > 0.6 \text{V}$		25		μΑ
I <sub>sh</sub>	Shutdown current	V <sub>cc</sub> < 2.7V, V <sub>FB</sub> > 0.6V		0.2		μΑ
I <sub>lx</sub>	LX leakage current (*)	$V_{cc}$ < 2.7V, $V_{LX}$ = $V_{cc}$		1		μΑ
		$V_{cc}$ < 2.7V, $V_{LX}$ = 0V		1		μΑ
ERROR AM	PLIFIER CHARACTERISTICS	1		I .		
$V_{fb}$	Voltage feedback		0.593	0.6	0.607	V
I <sub>fb</sub>	Feedback input current (*)	V <sub>FB</sub> = 0.6V		25		nA
SYNC/MOD	E FUNCTION	1	I	I	·I	
V <sub>sync_H</sub>	Sync mode threshold high				1.3	V
V <sub>sync_L</sub>	Sync mode threshold low		0.5			V
LB SECTIO	N			I	-I	<u> </u>
$V_{LBI}$	LBI Threshold			0.6		V
V <sub>LBO</sub>	LBO Logic Low	$I_{Sink} = 1 \text{mA}, \ V_{CC} = 3.6 \text{V}, \\ V_{LBI} < 0.6 \text{V}$		0.2	0.4	V
I <sub>LK-LBO</sub>	LBO Leakage Current (*)	$V_{\overline{LBO}} = 3.6V, V_{CC} = 3.6V, V_{LBI} > 0.6V$			50	nA
PROTECTIO	DNS		1	<u>I</u>	1	I
HOVP	Hard overvoltage threshold			10		%Vout
	1	i	1	l	1	1

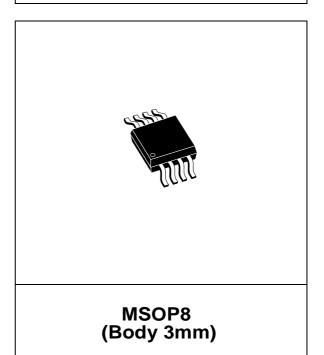
<sup>(\*)</sup> Guaranteed by design

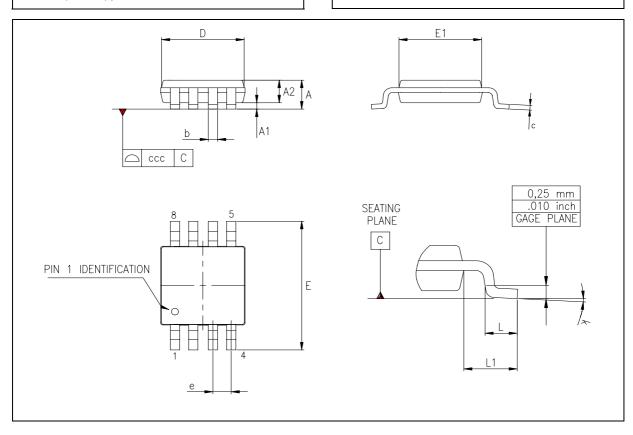
DIM.	mm			inch			
Diwi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			1.10			0.043	
A1	0.050		0.150	0.002		0.006	
A2	0.750	0.850	0.950	0.03	0.033	0.037	
b	0.250		0.400	0.010		0.016	
С	0.130		0.230	0.005		0.009	
D (1)	2.900	3.000	3.100	0.114	0.118	0.122	
Е	4.650	4.900	5.150	0.183	0.193	0.20	
E1 (1)	2.900	3.000	3.100	0.114	0.118	0.122	
е		0.650			0.026		
L	0.400	0.550	0.700	0.016	0.022	0.028	
L1		0.950			0.037		
k	0° (min.) 6° (max.)						
aaa			0.100			0.004	

Note: 1. D and F does not include mold flash or protrusions.

Mold flash or potrusions shall not exceed 0.15mm (.006inch) per side.

# OUTLINE AND MECHANICAL DATA





4/5

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics.
All other names are the property of their respective owners

© 2003 STMicroelectronics - All rights reserved

#### STMicroelectronics GROUP OF COMPANIES

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States www.st.com

